

MOS FIELD EFFECT POWER TRANSISTOR 2SK1853

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK1853 is N-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

Low On-state Resistance

R_{DS(on)} \leq 80 mΩ (V_{GS} = 10 V, I_D = 8.0 A) R_{DS(on)} \leq 0.1 Ω (V_{GS} = 4 V, I_D = 8.0 A)

- Low Ciss Ciss = 2 200 pF TYP.
- Built-in G-S Gate Protection Diode

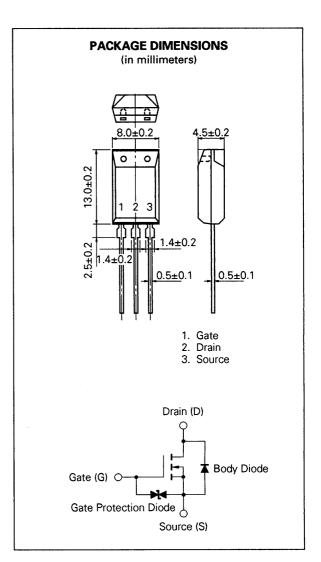
QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^{\circ}C$)

Drain to Source Voltage	Voss	100	٧
Gate to Source Voltage	VGSS(AC)	±20	V
Gate to Source Voltage	Vgss(DC)	+20, -10	V
Drain Current (DC)	ID(DC)	±15	Α
Drain Current (pulse)	D(pulse)*	±60	Α
Total Power Dissipation (Ta =	25 °C) PT	1.8	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
* PW ≦ 10 μs, Duty Cycle ≦ 1 %			

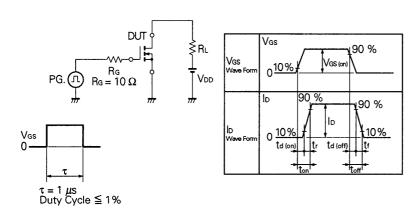




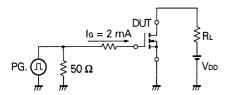
ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	RDS(on)		0.07	0.08	Ω	Vgs = 10 V, ID = 8 A
Drain to Source On-state Resistance	RDS(on)		0.08	0.10	Ω	Vgs = 4 V, lp = 8 A
Gate to Source Cutoff Voltage	Vgs(off)	1.0		2.5	V	Vps = 10 V, lp = 1 mA
Forward Transfer Admittance	yfs	11			S	Vps = 10 V, lp = 8 A
Drain Leakage Current	loss			10	μΑ	Vps = 100 V, Vgs = 0
Gate to Source Leakage Current	lgss			±10	μΑ	Vgs = ±20 V, Vps = 0
Input Capacitance	Ciss		2 200		pF	V _{DS} = 10 V V _{GS} = 0 f = 1 MHz
Output Capacitance	Coss		550		pF	
Reverse Transfer Capacitance	Сгвв		90		pF	
Turn-On Delay Time	td(on)		25		ns	$V_{GS(on)} = 10 \text{ V}$ $V_{DD} = 50 \text{ V}$ $I_D = 8 \text{ A}, R_G = 10 \Omega$ $R_L = 6.25 \Omega$
Rise Time	tr		85		ns	
Turn-Off Delay Time	td(off)		220		ns	
Fall Time	tr		90		ns	
Total Gate Charge	QG		50		nC	V _{GS} = 10 V I _D = 15 A V _{DD} = 80 V
Gate to Source Charge	Qgs		10		nC	
Gate to Drain Charge	Qgp		10		nC	
Diode Forward Voltage	VF(S-D)		1.0		٧	Vgs = 0, lp = 15 A
Reverse Recovery Time	trr		150		ns	I _F = 15 A, V _{GS} = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Qrr		300		nC	

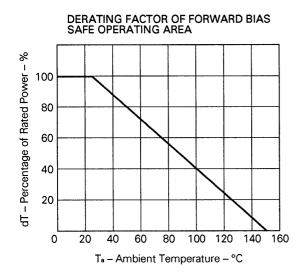
Test Circuit 1: Switching Time

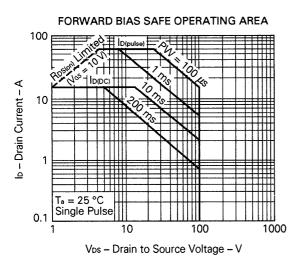


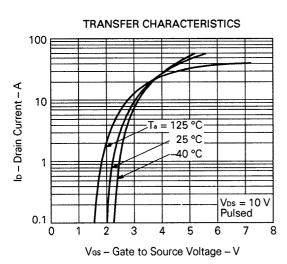
Test Circuit 2: Gate Charge

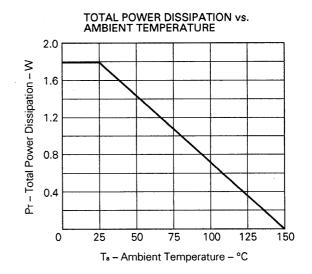


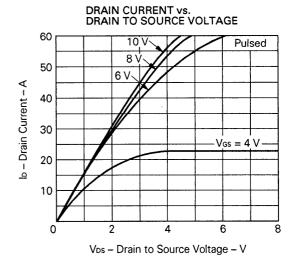
TYPICAL CHARACTERISTICS (Ta = 25 °C)

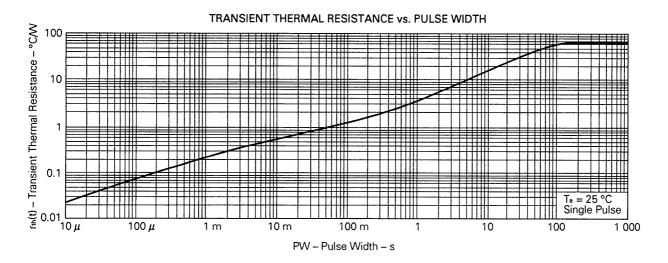


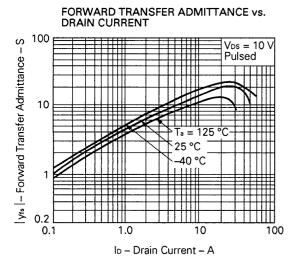


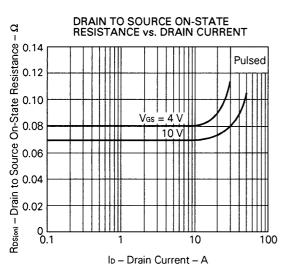


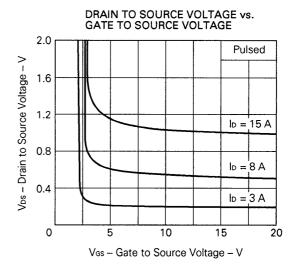


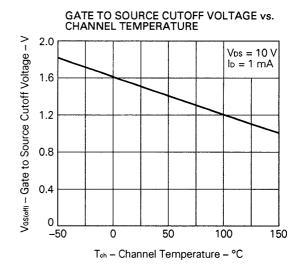


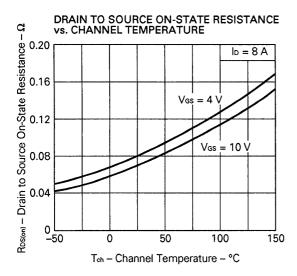


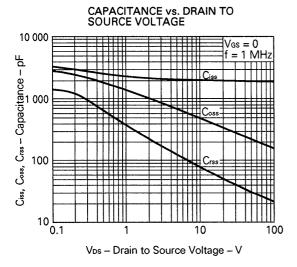


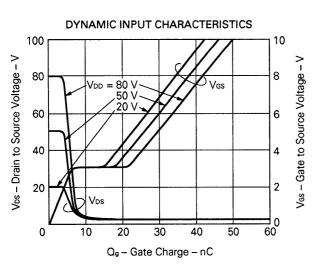


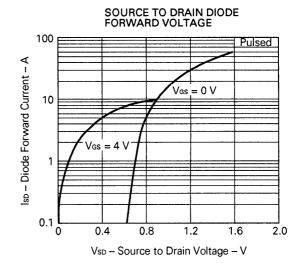


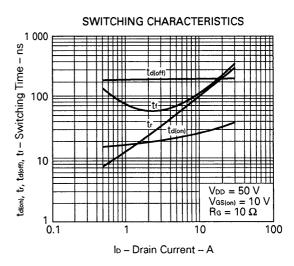


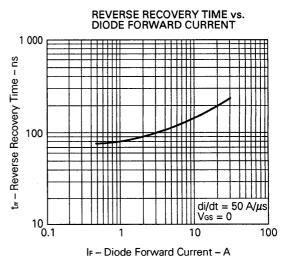












Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207

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Application examples recommended by NEC Corporation.

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